



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re Application of:)	PATENT APPLICATION
)	
Inventors: Katsuji Iguchi, Sheng Teng Hsu,)	
Yoshi Ono and Jer-shen Maa)	
)	
Serial No.: Not Yet Assigned)	Attorney Docket No.
)	SLA 0636
Filed: Herewith)	
)	
Title: METHOD OF FABRICATING)	
DEEP SUB-MICRON CMOS)	
SOURCE/DRAIN WITH MDD)	
AND SELECTIVE CVD SILICIDE)	
)	

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name; I believe that I am the original, first and sole inventor (if one name is listed below), or the first and joint inventor (if plural names are listed below), of the subject matter which is claimed and for which a patent is sought on the invention entitled,

**METHOD OF FABRICATING DEEP SUB-MICRON CMOS
SOURCE/DRAIN WITH MDD AND SELECTIVE CVD SILICIDE**

the specification of which (check applicable ones):

- ☒ is attached hereto;
- ☐ was filed with the above-identified "Filed" date and assigned the above-identified "Serial No.";
- ☐ was amended on (or amended through) _____.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by an amendment(s) referred to above. I acknowledge the duty to disclose information which is material to the examination of the application in accordance with Title 37, Code of Federal Regulations, §1.56.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Full name of sole
or first inventor:

Katsuji Iguchi

Residence:

46-10 Izumihara
Yamato-Koriyama, Nara 639-1058
Japan

Post Office Address:

Same

Citizenship:

Japan

Inventor's signature:



Date:

10/26/01

Full name of sole
or second inventor: Sheng Teng Hsu

Residence: 2216 NW Trout Court
Camas, WA 98607

Post Office Address: Same

Citizenship: United States

Inventor's signature: Sheng Teng Hsu

Date: 10/25/01

Full name of sole
or third inventor: Yoshi Ono

Residence: 2526 NW 24th Circle
Camas, WA 98607

Post Office Address: Same

Citizenship: United States

Inventor's signature: [Signature]

Date: 10/25/01

Full name of sole
or fourth inventor: Jer-shen Maa

Residence: 1511 SE Solomon Loop
Vancouver, WA 98683

Post Office Address: Same

Citizenship: United States

Inventor's signature: Jer-shen Maa

Date: 10/25/2001
